

BCR1AM-8P

400V-1A-Triac

Low Power Use

R07DS0178EJ0200

Rev.2.00

Aug 25,2015

Features

- $I_{T(RMS)}$: 1 A
- V_{DRM} :400 V
- I_{FGTI} : 5 mA
- I_{RGTI}, I_{RGTH} : 5 mA or 3mA(I_{GT} item:1)
- I_{FGTH} : 10 mA
- Non-Insulated Type
- Planar Passivation Type
- RoHS Compliant
- Halogen-free package (PRSS0003DJ-A)
- Completely Pb-free package (PRSS0003DJ-A)

Outline

RENESAS Package code: PRSS0003EA-A
(Package name: TO-92*)

RENESAS Package code: PRSS0003DJ-A
(Package name: TO-92)



1. T₁ Terminal
2. T₂ Terminal
3. Gate Terminal

Applications

Contactless AC switch, fan motor, rice-cooker, electric pot, air cleaner, heater, refrigerator, washing machine, electric fan, vending machine, trigger circuit for low and medium triac, and other general purpose control applications

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		8	
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	400	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	500	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T(RMS)}$	1.0	A	Commercial frequency, sine full wave 360° conduction, $T_c = 56^{\circ}\text{C}$ ^{Note3}
Surge on-state current	I_{TSM}	10	A	60Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusing	I^2t	0.41	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P_{GM}	1	W	
Average gate power dissipation	$P_{G(AV)}$	0.1	W	
Peak gate voltage	V_{GM}	6	V	
Peak gate current	I_{GM}	0.5	A	
Junction temperature	T_j	- 40 to +125	°C	
Storage temperature	T_{stg}	- 40 to +125	°C	
Mass	—	0.23	g	Typical value

Notes: 1. Gate open.

Electrical Characteristics

Parameter	Symbol	Rated value			Unit	Test conditions
		Min.	Typ.	Max.		
Repetitive peak off-state current	I_{DRM}	—	—	0.5	mA	$T_j = 125^\circ\text{C}$, V_{DRM} applied
On-state voltage	V_{TM}	—	—	1.6	V	$T_c = 25^\circ\text{C}$, $I_{TM} = 1.5\text{ A}$, Instantaneous measurement
Gate trigger voltage ^{Note2}	I	V_{FGTI}	—	—	2.0	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II	V_{RGTI}	—	—	2.0	
	III	V_{RGTIII}	—	—	2.0	
	IV	V_{FGTIII}	—	—	2.0	
Gate trigger current ^{Note2}	I	I_{FGTI}	—	—	5	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II	I_{RGTI}	—	—	5 ^{Note5}	
	III	I_{RGTIII}	—	—	5 ^{Note5}	
	IV	I_{FGTIII}	—	—	10	
Gate non-trigger voltage	V_{GD}	0.1	—	—	V	$T_j = 125^\circ\text{C}$, $V_D = 1/2 V_{DRM}$
Thermal resistance	$R_{th(j-c)}$	—	—	50	$^\circ\text{C/W}$	Junction to case ^{Note3}
Critical-rate of rise of off-state commutating voltage ^{Note4}	$(dv/dt)_c$	2	—	—	$\text{V}/\mu\text{s}$	$T_j = 125^\circ\text{C}$

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

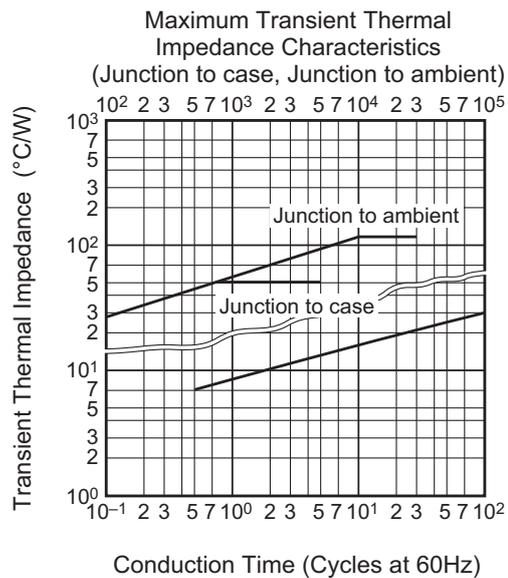
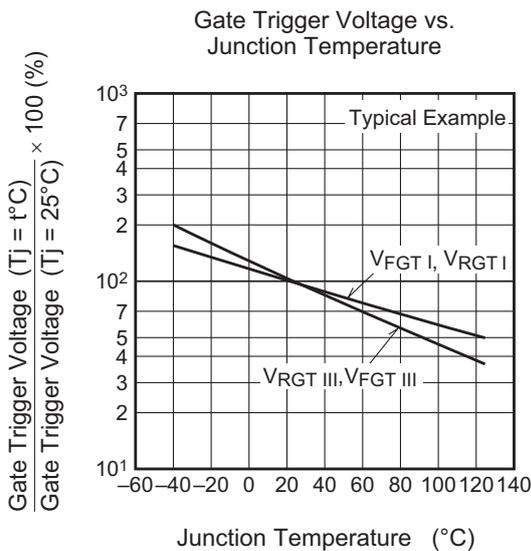
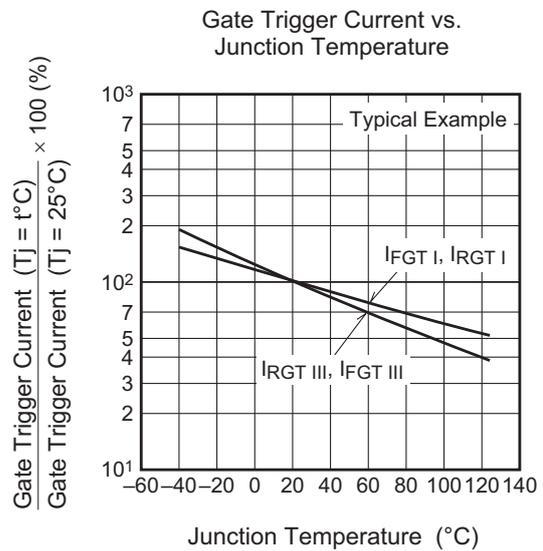
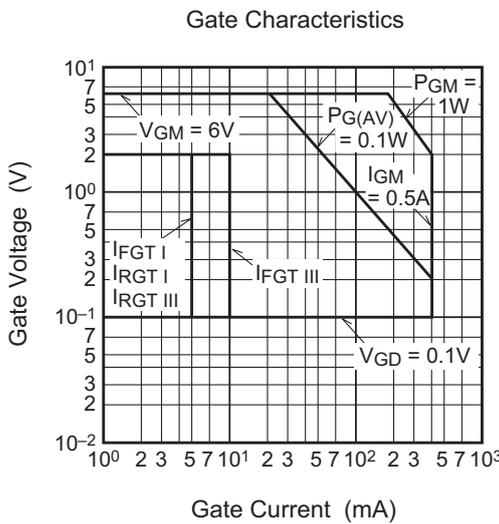
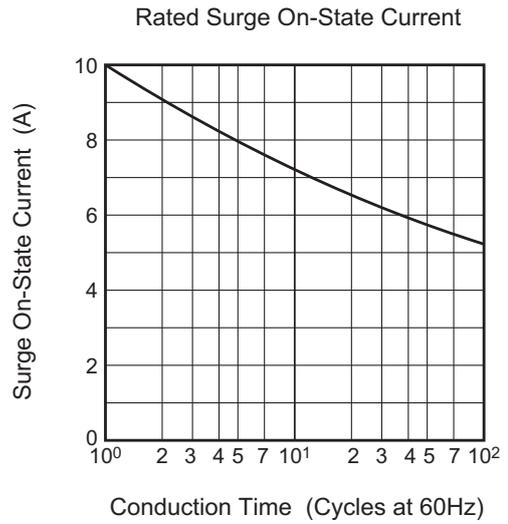
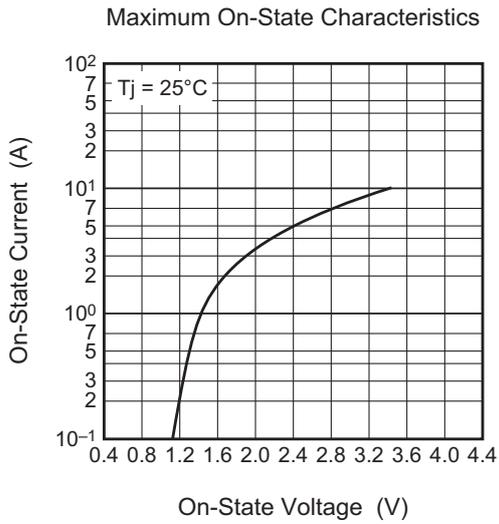
3. Case temperature is measured at the T_2 terminal 1.5 mm away from the molded case.

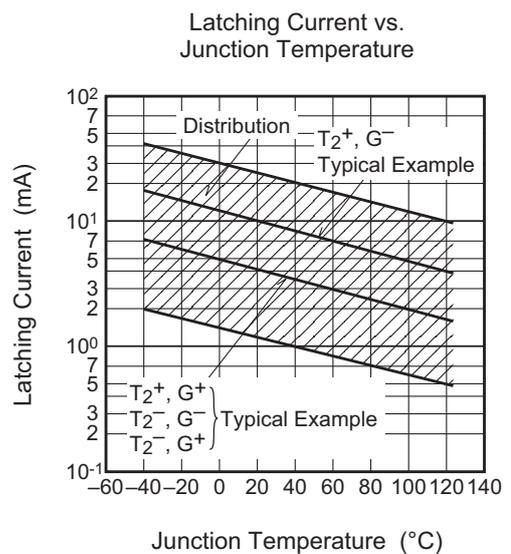
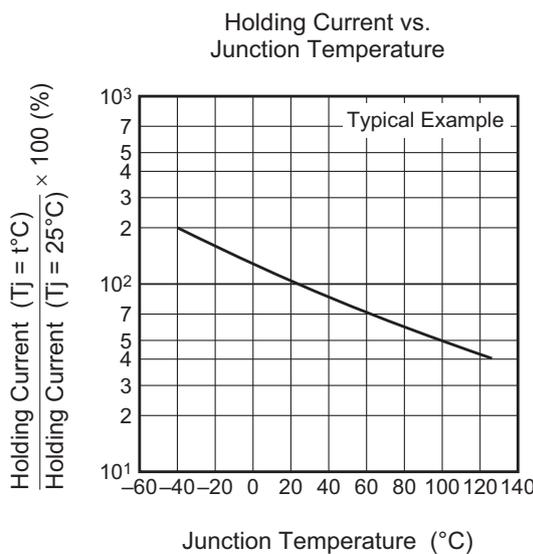
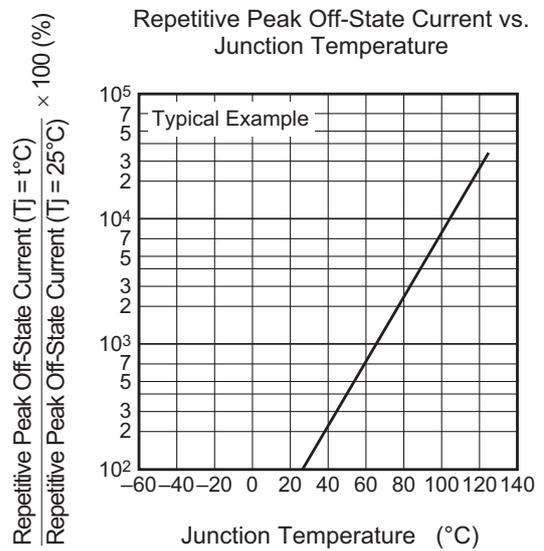
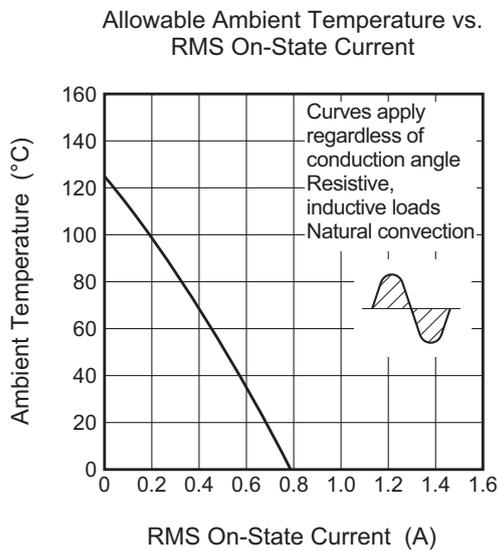
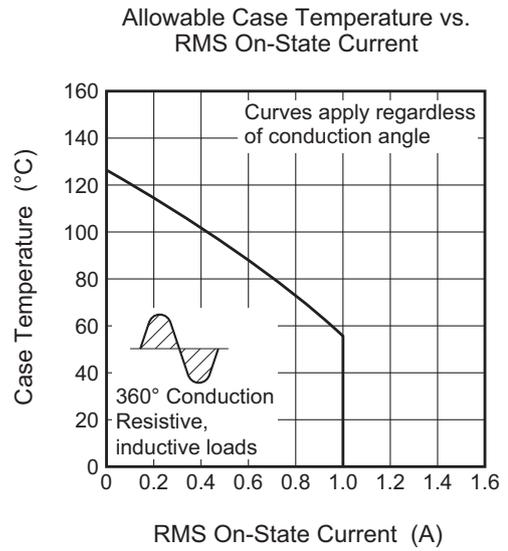
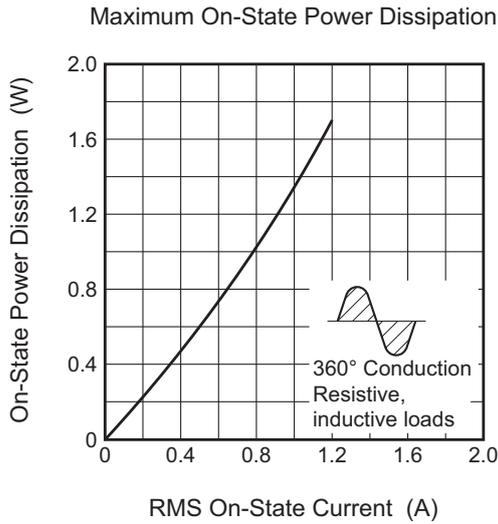
4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

5. High sensitivity ($I_{GT} \leq 3\text{ mA}$) is also available. (I_{GT} item: 1)

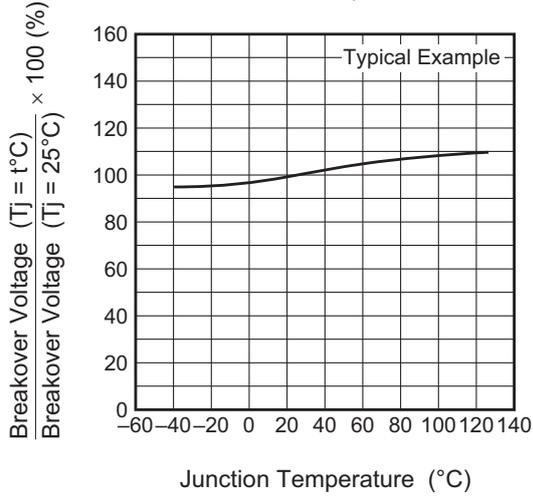
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_j = 125^\circ\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_c = -0.5\text{ A/ms}$ 3. Peak off-state voltage $V_D = 400\text{ V}$	

Performance Curves

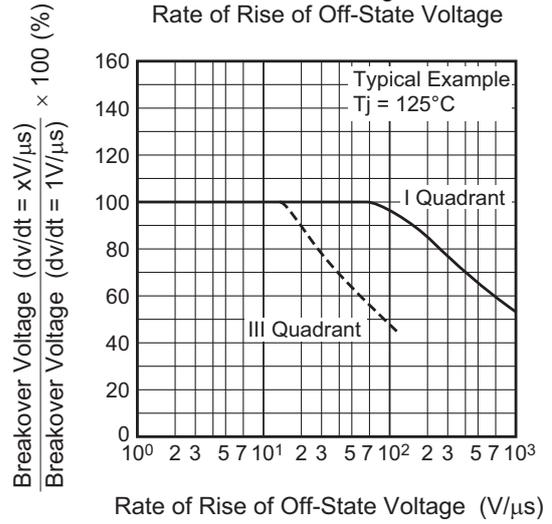




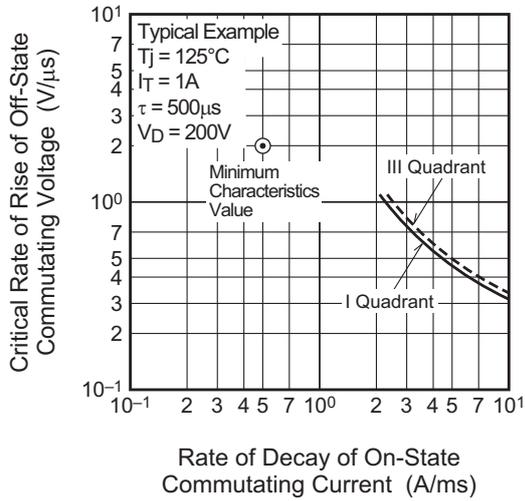
Breakover Voltage vs. Junction Temperature



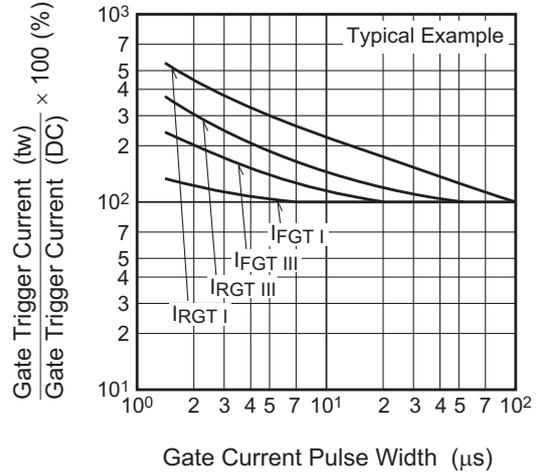
Breakover Voltage vs. Rate of Rise of Off-State Voltage



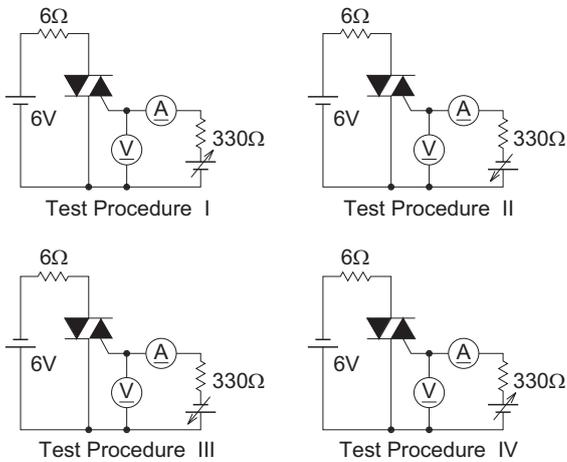
Commutation Characteristics



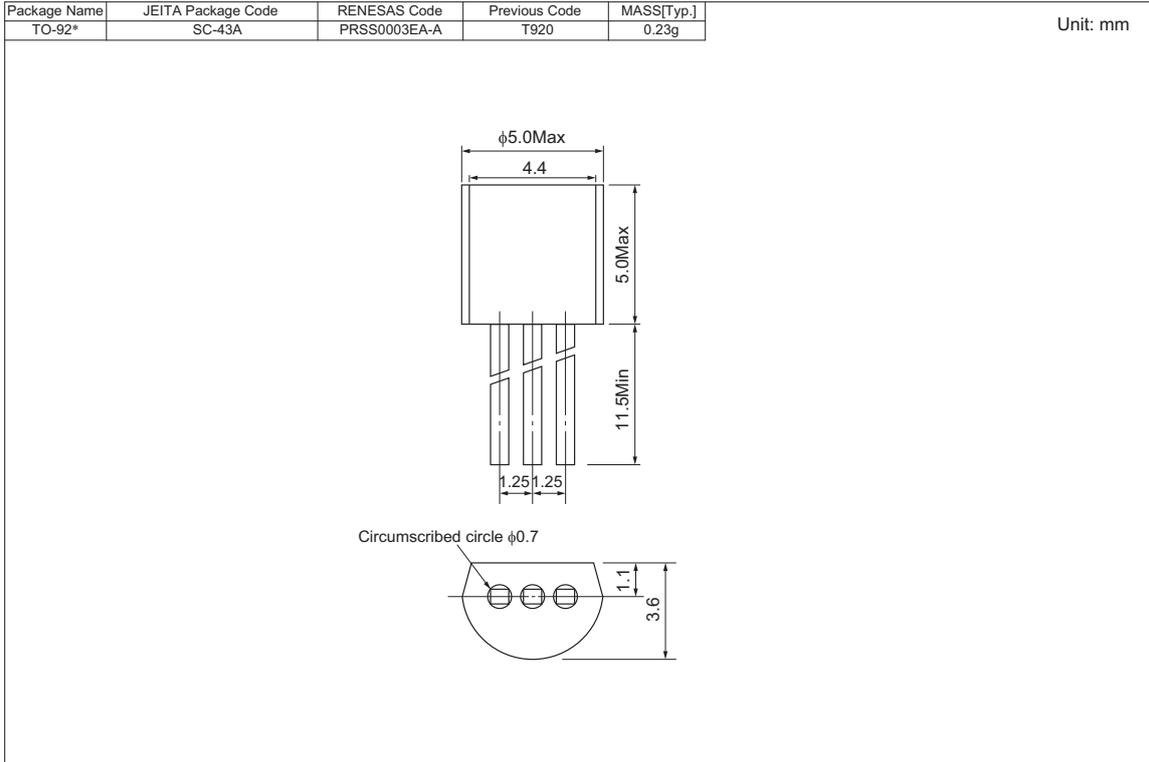
Gate Trigger Current vs. Gate Current Pulse Width



Gate Trigger Characteristics Test Circuits

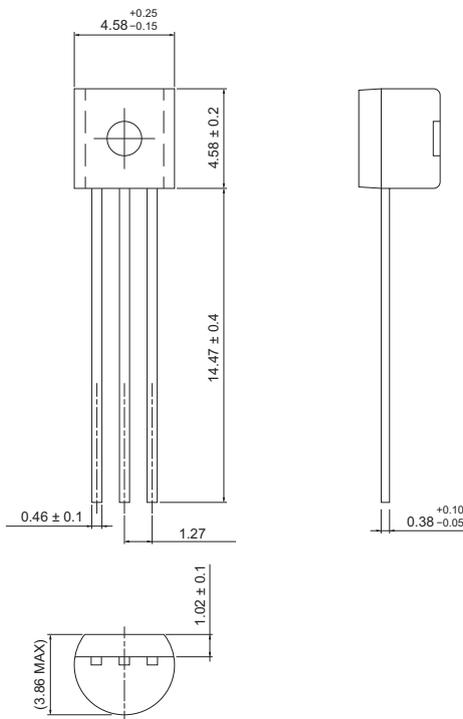


Package Dimensions



JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-43A	PRSS0003DJ-A	TO-92	0.23

Unit: mm



Ordering Information

Orderable Part Number	Package	Packing ^{Note}	Quantity	Remark
BCR1AM-8P#B00	TO-92*	Plastic Bag	500 pcs.	Straight type
BCR1AM-8P-1#B00	TO-92*	Plastic Bag	500 pcs.	Straight type, I _{GT} item:1
BCR1AM-8P-A6#B00	TO-92*	Plastic Bag	500 pcs.	A6 Lead form
BCR1AM-8P-1A6#B00	TO-92*	Plastic Bag	500 pcs.	A6 Lead form, I _{GT} item:1
BCR1AM-8P-TB#B00	TO-92*	Adhesive Tape	2000 pcs.	A8 Lead form
BCR1AM-8P-1TB#B00	TO-92*	Adhesive Tape	2000 pcs.	A8 Lead form, I _{GT} item:1
BCR1AM-8P#BD0	TO-92	Plastic Bag	1000 pcs.	Straight type, Halogen-free
BCR1AM-8P-1#BD0	TO-92	Plastic Bag	1000 pcs.	Straight type, Halogen-free, I _{GT} item:1
BCR1AM-8P-A6#BD0	TO-92	Plastic Bag	1000 pcs.	A6 Lead form, Halogen-free
BCR1AM-8P-1A6#BD0	TO-92	Plastic Bag	1000 pcs.	A6 Lead form, Halogen-free, I _{GT} item:1
BCR1AM-8P-TB#BD0	TO-92	Adhesive Tape	2000 pcs.	A8 Lead form, Halogen-free
BCR1AM-8P-1TB#BD0	TO-92	Adhesive Tape	2000 pcs.	A8 Lead form, Halogen-free, I _{GT} item:1

Note : Please confirm the specification about the shipping in detail.

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